L Number	Hits	S arch Text	DB	Time stamp
-	2	("6008128").PN.	USPAT;	2002/09/17
			US-PGPUB;	09:09
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	576	(359/223).CCLS.	USPAT;	2002/09/17
			US-PGPUB;	09:09
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	255	(359/298). <i>CC</i> LS.	USPAT;	2002/09/17
			US-PGPUB;	09:09
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	505	(359/838). <i>CC</i> LS.	USPAT;	2002/09/17
	0		US-PGPUB;	09:13
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	88	(205/116). <i>CC</i> LS.	USPAT;	2002/09/17
			US-PGPUB;	09:14
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	135	((359/223).CCLS.) and silicon\$	USPAT;	2002/09/17
			US-PGPUB;	09:20
			EPO; JPO;	
			DERWENT;	
`			IBM_TDB	
-	85	((359/298).CCLS.) and silicon\$	USPAT;	2002/09/17
			US-PGPUB;	10:21
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	66	((359/838).CCLS.) and silicon\$	USPAT;	2002/09/17
			US-PGPUB;	10:30
			EPO; JPO;	
			DERWENT;	
			IBW_TDB	
-	8	((205/116).CCLS.) and silicon\$	USPAT;	2002/09/17
			US-PGPUB;	10:33
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	421	silicon and mirror and bulk and monolith\$ and	USPAT;	2002/09/17
		crystal\$4	US-PGPUB;	10:43
	İ		EPO; JPO;	
			DERWENT;	
			IBM_TDB	

-	46	(silicon and mirror and bulk and monolith\$ and	USPAT;	2002/09/17
		crystal\$4) and inlet and outlet	US-PGPUB;	10:37
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	31	silicon and mirror and bulk and monolith\$ and	USPAT;	2002/09/17
		(crystal\$4 adj plane)	US-PGPUB;	10:51
		(crystalp+ adj plane)	EPO; JPO;	10.51
			DERWENT;	
			IBM_TDB	
	89	(single adj crystal adj silicon) and mirror and	USPAT;	2002/09/17
-	0,9	(crystal\$4 adj plane)	US-PGPUB;	11:08
		(crystal \$4 adj plane)	EPO; JPO;	11.00
1			DERWENT;	
			IBM_TDB	
	692	(single adj crystal adj silicon) and mirror and plane	USPAT;	2002/09/17
_	092		US-PGPUB;	11:43
		and etch\$3	EPO; JPO;	11.45
			DERWENT;	
	300	//	IBM_TDB	2002/00/17
_	309	((single adj crystal adj silicon) and mirror and plane	USPAT;	2002/09/17
		and etch\$3) and anisotrop\$	US-PGPUB;	11:09
			EPO; JPO;	
			DERWENT;	
	101		IBM_TDB	0000 100 117 14 10
-	101	(((single adj crystal adj silicon) and mirror and plane	USPAT;	2002/09/17 11:10
]		and etch\$3) and anisotrop\$) and fiber and optic\$4	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	404		IBM_TDB	0000 100 117 4 4 4
-	121	(single and crystal and silicon) and mirror and plane	USPAT;	2002/09/17 14:11
		and etch\$3 and anisotrop\$ and fiber and optic\$4 and	US-PGPUB;	
		internal\$2	EPO; JPO;	
			DERWENT;	
	^=.	atural constant that the state of the state	IBM_TDB	2000/00/47
-	256	single and crystal\$4 and silicon and mirror and	USPAT;	2002/09/17
		etch\$3 and stripe and intersect\$4	US-PGPUB;	14:25
	i		EPO; JPO;	
			DERWENT;	
		, , , , , , , , , , , , , , , , , , ,	IBM_TDB	
-	118	(single and crystal\$4 and silicon and mirror and	USPAT;	2002/09/17
		etch\$3 and stripe and intersect\$4) and internal	US-PGPUB;	11:58
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	373	(single near crystal\$4 near silicon) with mirror	USPAT;	2002/09/17
			US-PGPUB;	12:05
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	

-	39	((single near crystal\$4 near silicon) with mirror) and	USPAT;	2002/09/17
		(fiber n ar optic\$4)	US-PGPUB;	12:06
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	3645	digital and mirror and d vice and silicon and	USPAT;	2002/09/17
		crystal\$4	US-PGPUB;	14:12
		,	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	168	(digital and mirror and device and silicon and	USPAT;	2002/09/17
	100	crystal\$4) and bulk and monolith\$	US-PGPUB;	14:12
		crystalpa) and balk and monorma	EPO; JPO;	14.16
			DERWENT;	
	341	attions and minus and abolige and about a suit	IBM_TDB	2002 (00 (17
-	341	silicon and mirror and etch\$3 and stripe and	USPAT;	2002/09/17
		intersect\$4	US-PGPUB;	14:36
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	2259	silicon and mirror and pattern\$3 and anisotrop\$	USPAT;	2002/09/17
			US-PGPUB;	14:37
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	403	(single adj crystal\$4 adj silicon) and mirror and	USPAT;	2002/09/17
		pattern\$3 and anisotrop\$	US-PGPUB;	15:20
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	0	(bulk with (single adj crystal\$4 adj silicon)) and	USPAT;	2002/09/17
		(mirror near pattern\$3)	US-PGPUB;	15:22
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	20	silicon and (mirror near pattern\$3) and (anisotrop\$	USPAT;	2002/09/17
		near etch\$3)	US-PGPUB;	15:34
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	16	silicon and ((mirror near pattern\$3) with array\$)	USPAT;	2002/09/17
		(Lance	US-PGPUB;	15:39
]		EPO; JPO;	
			DERWENT;	
			IBM_TDB	
	2585	(mirror with array\$) and silicon	USPAT;	2002/09/17
	2303	(mill of with dirayy) and sincon	US-PGPUB;	
			The state of the s	16:16
			EPO; JPO;	
			DERWENT;	
	ı i		IBM_TDB	1

	9	(mirror with array\$) and (bulk with single with	USPAT;	2002/09/17
-		crystal\$4 with silicon)	US-PGPUB;	15:43
		Crystalp+ with silicon)	EPO; JPO;	13.73
			DERWENT;	
			IBM_TDB	
		((,,, the, the) and animal through and		2002/00/17
-	2	((mirror with array\$) and silicon) and anisotrop\$ and	USPAT;	2002/09/17
	İ	(bulk near crystal\$4)	US-PGPUB;	15:44
			EPO; JPO;	
			DERWENT;	
	_		IBW_TDB	
-	2	monolithic adj bulk adj crystal adj silicon	USPAT;	2002/09/17
			US-PGPUB;	16:17
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	2	monolithic with bulk with crystal with silicon	USPAT;	2002/09/17
		•	US-PGPUB;	16:17
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	1586	monolithic and bulk and crystal and silicon	USPAT;	2002/09/17
	1300	monorthic and bank and crystal and sincon	US-PGPUB;	16:18
			EPO; JPO;	10.10
			DERWENT;	
			1	
	25	(manalish); and holls and amostal and silican) and	IBM_TDB	2002/00/17
-	25	(monolithic and bulk and crystal and silicon) and	USPAT;	2002/09/17
		(crystalline near plane)	US-PGPUB;	16:19
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	362	(monolithic and bulk and crystal and silicon) and	USPAT;	2002/09/17
		(crystalline and plane)	US-PGPUB;	16:20
			EPO; JPO;	1
			DERWENT;	
			IBW_LDB	}
-	4	((monolithic and bulk and crystal and silicon) and	USPAT;	2002/09/17
		(crystalline and plane)) and (micro?mirror or (micro	US-PGPUB;	16:20
		adj mirror))	EPO; JPO;	
			DERWENT;	
	1		IBM_TDB	
-	109	((monolithic and bulk and crystal and silicon) and	USPAT;	2002/09/17
		(crystalline and plane)) and mirror	US-PGPUB;	16:41
		,	EPO; JPO;	
]		DERWENT;	
			IBM_TDB	
_	4	silicon near mirror near array	USPAT;	2002/09/17
		The second second second	US-PGPUB;	16:42
			EPO; JPO;	-0.15
			DERWENT;	
			IBM_TDB	
	1		I TOW_IUD	1

_	1415	digital near (micromirror or micro?mirror or (micro	USPAT;	2002/09/17
		adj mirror)) near d vice	US-PGPUB;	16:43
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	350	(digital near (micromirror or micro?mirror or (micro	USPAT;	2002/09/17
		adj mirror)) near device) and silicon	US-PGPUB;	17:12
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	16	(digital near (micromirror or micro?mirror or (micro	USPAT;	2002/09/17
		adj mirror)) near device) and (single adj crystal adj	US-PGPUB;	17:14
		silicon)	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	3991	(mirror or reflect\$) and (single adj crystal adj	USPAT;	2002/09/17
		silicon)	US-PGPUB;	17:16
			EPO; JPO;	ļ
			DERWENT;	
			IBM_TDB]
-	240	((mirror or reflect\$) and (single adj crystal adj	USPAT;	2002/09/17
		silicon)) and bulk and monolith\$	US-PGPUB;	17:42
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	148	anisotrop\$ with silicon with array with etch\$4	USPAT;	2002/09/17
			US-PGPUB;	17:43
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	226	(anisotrop\$ with silicon with process\$) and (mirror or	USPAT;	2002/09/17
		reflector)	US-PGPUB;	18:38
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	25	silicon and mirror and passage and (crystalline adj	USPAT;	2002/09/17
		plane)	US-PGPUB;	18:42
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	42	(monolithic and bulk and crystal and silicon) and	USPAT;	2002/09/17
		(mirror or reflector) and crystalline and plane and	US-PGPUB;	18:44
		intersect\$4	EPO; JPO;	
			DERWENT;	
			IBM_TDB	